

Application No. 10/522,887
Supplemental Preliminary Amendment
October 16, 2006

AMENDMENTS TO THE SPECIFICATION

Please substitute the heading beginning on page 15, line 8 and ending at line 19 as follows:

Japanese Unexamined Patent Application Publication No. 2001-313422 (page 6, right column, line 8 to page 7, left column, line 42, Figs. 8 and 9) has disclosed a method is liable to result in a short circuit between the p layer and the n layer at the cross-section between the devices (side surfaces of the device after cutting), disadvantageously. Accordingly, a second object (first and second light-emitting devices) of the present invention is to provide a nitride semiconductor light-emitting device having a structure capable of preventing a short circuit at the side surfaces, and a method for manufacturing the same. Japanese Unexamined Patent Application Publication No. ~~3-330629~~ 8-330629 (Figs. 1 to 3) has been known.